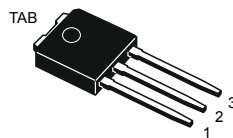
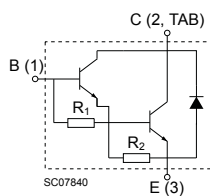


Low voltage NPN power Darlington transistor


IPAK

 NPN: $R_1 = 7\text{ k}\Omega$, $R_2 = 70\text{ }\Omega$


Features

- Low collector-emitter saturation voltage
- Monolithic Darlington configuration with integrated antiparallel collector-emitter diode

Application

- Linear and switching industrial equipment

Description

This device is manufactured in planar technology with “base island” layout and monolithic Darlington configuration.

Product status links

[MJD122-1](#)

Product summary

Order code	MJD122-1
Marking	MJD122
Polarity	NPN
Package	IPAK
Packing	Tube

1 Electrical ratings

Table 1. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CEO}	Collector-emitter voltage ($I_B = 0$ A)	100	V
V_{CBO}	Collector-base voltage ($I_E = 0$ A)		V
V_{EBO}	Emitter-base voltage ($I_C = 0$ A)	5	V
I_C	Collector current	8	A
I_{CM}	Collector peak current	16	A
I_B	Base current	120	mA
P_{TOT}	Total power dissipation at $T_C = 25$ °C	20	W
T_{stg}	Storage temperature range	-65 to 150	°C
T_J	Operating junction temperature range		

Table 2. Thermal data

Symbol	Parameter	Value	Unit
R_{thJC}	Thermal resistance, junction-to-case	6.25	°C/W

2 Electrical characteristics

$T_C = 25^\circ\text{C}$ unless otherwise specified.

Table 3. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{CBO}	Collector cut-off current	$V_{CB} = 100\text{ V}, I_E = 0\text{ A}$		-	10	μA
I_{CEO}	Collector cut-off current	$V_{CE} = 50\text{ V}, I_B = 0\text{ A}$		-	10	μA
I_{EBO}	Emitter cut-off current	$V_{EB} = 5\text{ V}, I_C = 0\text{ A}$		-	2	mA
$V_{CEO(sus)}^{(1)}$	Collector-emitter sustaining voltage	$I_C = 30\text{ mA}, I_B = 0\text{ A}$	100	-		V
$V_{CE(sat)}^{(1)}$	Collector-emitter saturation voltage	$I_C = 4\text{ A}, I_B = 16\text{ mA}$		-	2	V
		$I_C = 8\text{ A}, I_B = 80\text{ mA}$		-	4	
$V_{BE(sat)}^{(1)}$	Base-emitter saturation voltage	$I_C = 8\text{ A}, I_B = 80\text{ mA}$		-	4.5	V
$V_{BE(on)}$	Base-emitter on voltage	$I_C = 4\text{ A}, V_{CE} = 4\text{ V}$		-	2.8	V
$h_{FE}^{(1)}$	DC current gain	$I_C = 4\text{ A}, V_{CE} = 4\text{ V}$	1000	-	12000	
		$I_C = 8\text{ A}, V_{CE} = 4\text{ V}$	100	-		

1. Pulse test: pulse duration $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.

2.1 Electrical characteristics (curves)

Figure 1. Safe operating area

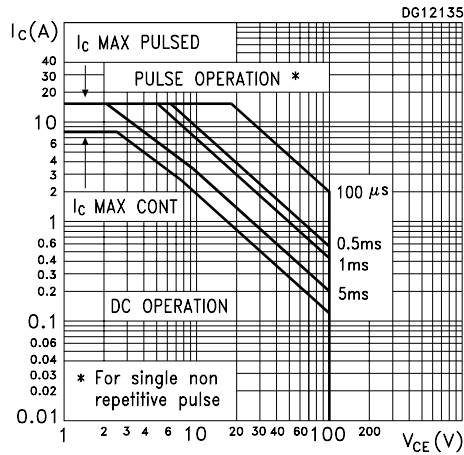


Figure 2. Derating curve

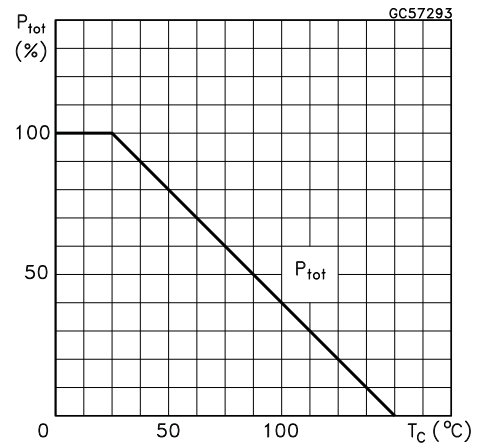


Figure 3. DC current gain

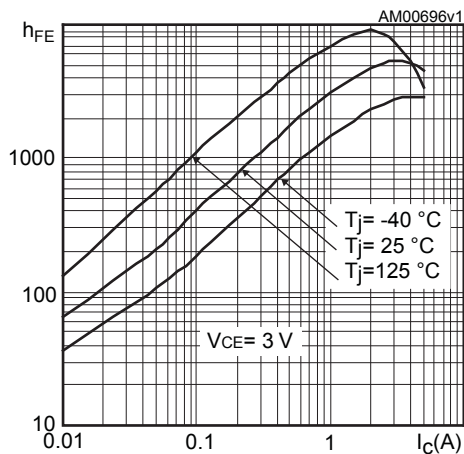


Figure 4. Collector-emitter saturation voltage

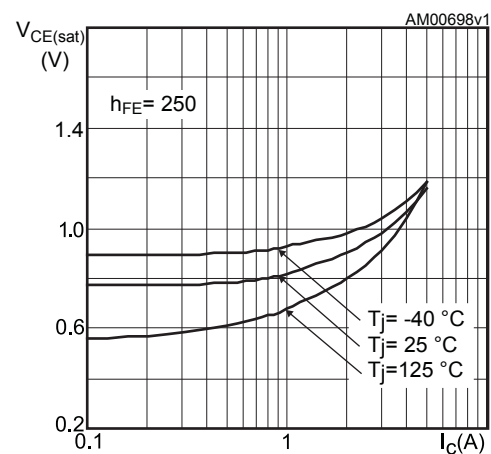


Figure 5. Base-emitter saturation voltage

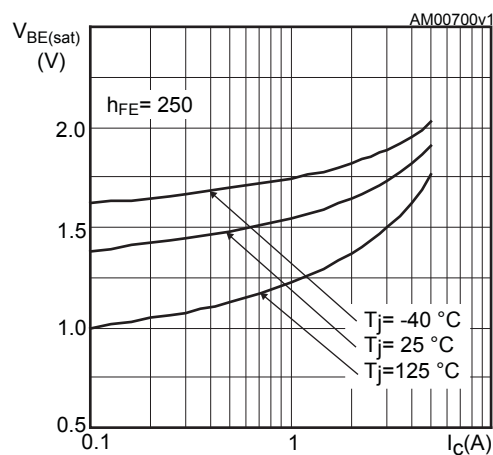


Figure 6. Base-emitter on voltage

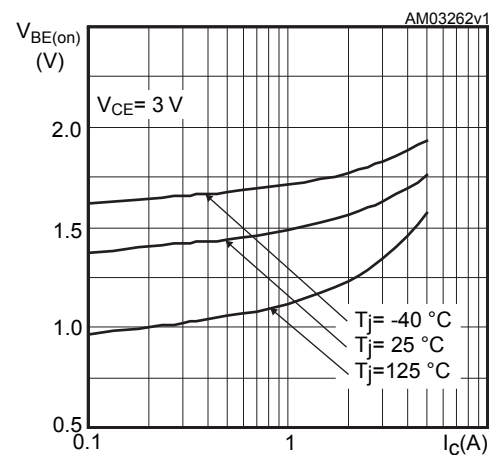


Figure 7. Resistive load switching time (on)

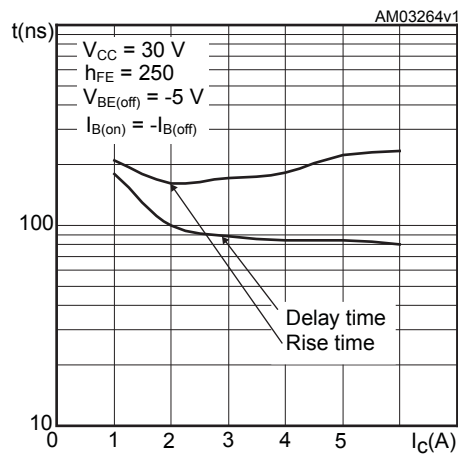


Figure 8. Resistive load switching time (off)

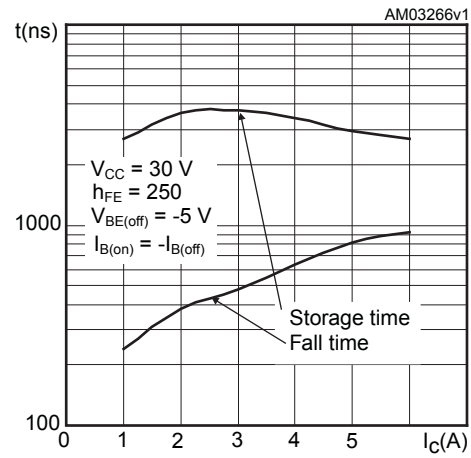
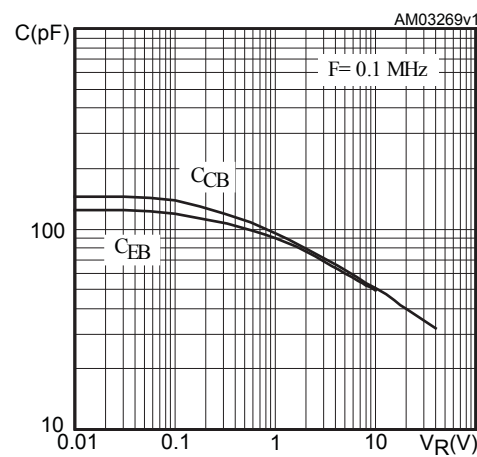
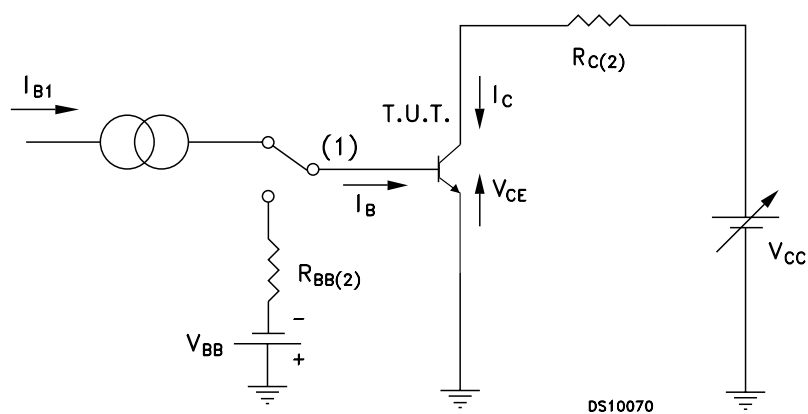


Figure 9. Capacitance characteristics



3 Test circuits

Figure 10. Resistive load switching test circuit



Note: (1) Fast electronic switch.

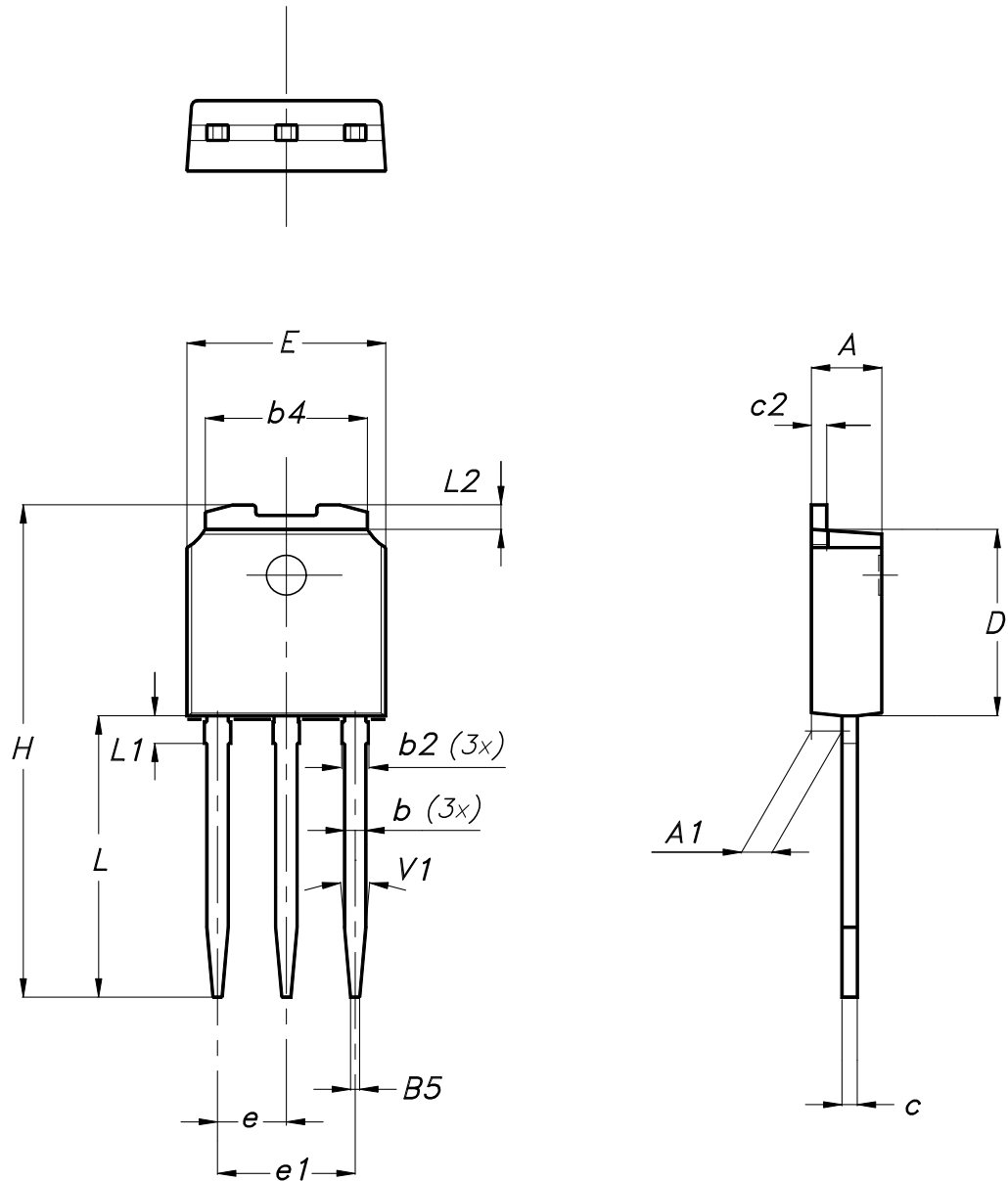
Note: (2) Non-inductive resistor.

4 Package information

To meet environmental requirements, ST offers these devices in different grades of **ECOPACK** packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions, and product status are available at: www.st.com. ECOPACK is an ST trademark.

4.1 IPAK (TO-251) type A package information

Figure 11. IPAK (TO-251) type A package outline



0068771_A_rev.16

Table 4. IPAK (TO-251) type A package mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A	2.20		2.40
A1	0.90		1.10
b	0.64		0.90
b2			0.95
b4	5.20		5.40
B5		0.30	
c	0.45		0.60
c2	0.48		0.60
D	6.00		6.20
E	6.40		6.60
e		2.28	
e1	4.40		4.60
H		16.10	
L	9.00		9.40
L1	0.80		1.20
L2		0.80	1.00
V1		10°	

Revision history

Table 5. Document revision history

Date	Revision	Changes
30-Apr-2025	1	First release.
16-Jun-2025	2	Updated. Table 3. Electrical characteristics .

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